





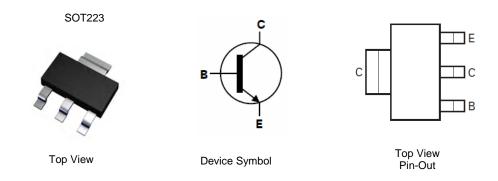
400V NPN HIGH VOLTAGE TRANSISTOR IN SOT223

Features

- BV_{CEO} > 400V
- I_C = 500mA High Continuous Current
- I_{CM} = 1A Peak Pulse Current
- Low Saturation Voltage V_{CE(SAT)} < 250mV @ 50mA
- h_{FE} > 40 Specified up to 200mA for High Current Gain Hold Up
- Complementary PNP Type: FZT758
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 63
- Weight: 0.112 grams (approximate)



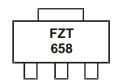
Ordering Information (Notes 4)

Product	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT658TA	FZT658	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information



FZT658 = Product type Marking Code





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	400	V
Collector-Emitter Voltage	V _{CEO}	400	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	0.5	Α
Peak Pulse Current	I _{CM}	1	А

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	D	2	W
Power Dissipation	(Note 6)	P _D	3	W
Thermal Resistance, Junction to Ambient	(Note 5)	В	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R• JA	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 7	R• JL	12.93	°C/W	
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	• 4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	• 400	V	С

Notes:

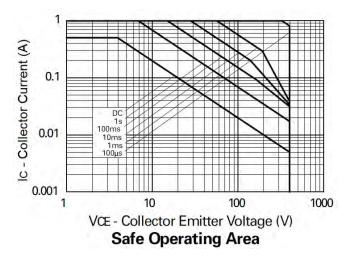
- 6. Same as note (5), except the device is mounted on 50mm X 50mm single sided 2oz weight copper.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

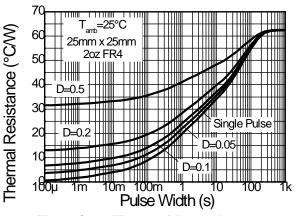
^{5.} For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.

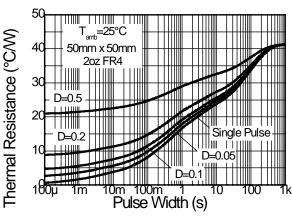




Thermal Characteristics and Derating Information

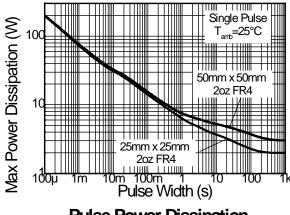


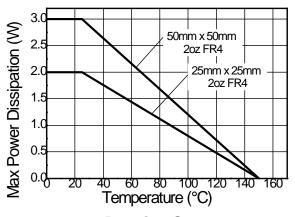




Transient Thermal Impedance







Pulse Power Dissipation

Derating Curve





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

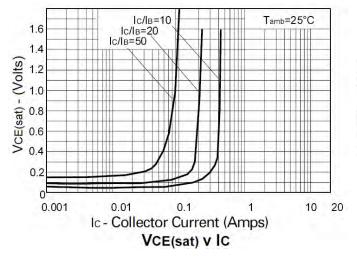
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	400	-	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	400	-	-	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	-	_	V	I _E = 100μA
Collector Cut-off Current	I _{CBO}	-	-	100	nA	V _{CB} = 320V
Emitter Cut-off Current	I _{EBO}	-	-	100	nA	V _{EB} = 6V
		-	-	0.30	V	I _C = 20mA, I _B = 1mA
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}			0.25		I _C = 50mA, I _B = 5mA
				0.50		I _C = 100mA, I _B = 10mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	-	-	0.9	V	I _C = 100mA, I _B = 10mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	-	-	1.0	V	I _C = 100mA, V _{CE} = 5V
		50	-	-		$I_C = 1mA$, $V_{CE} = 5V$
DC Current Gain (Note 9)	h _{FE}	50	-	_	_	I _C = 100mA, V _{CE} = 5V
		40	-	_		I _C = 200mA, V _{CE} = 10V
Current Gain-Bandwidth Product (Note 9)	f _T	50	_	-	MHz	$V_{CE} = 20V$, $I_C = 10mA$, $f = 20MHz$
Output Capacitance (Note 9)	C _{obo}	-	10	-	pF	V _{CB} = 20V, f = 1MHz
Switching Times	t _{on}	-	130	-	20	I _C = 100mA, V _{CC} = 100V
Switching Times	t _{off}	-	3,300	_	ns	$I_{B1} = 10 \text{mA}, I_{B2} = -20 \text{mA}$

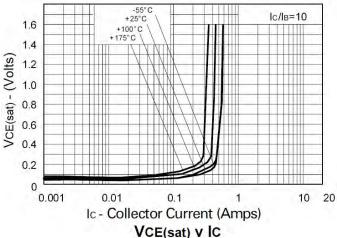
Note:

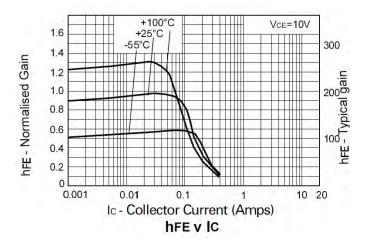
9. Measured under pulsed conditions. Pulse width • 300µs. Duty cycle • 2%

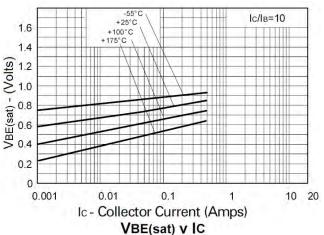


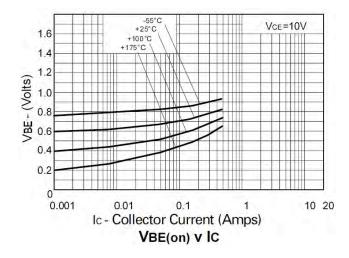
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









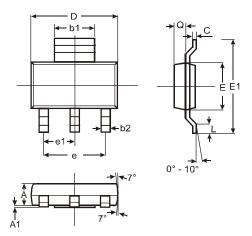






Package Outline Dimensions

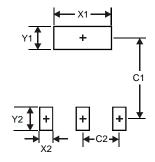
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е		_	4.60		
e1		_	2.30		
L	0.85	1.05	0.95		
q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.





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